D ynam ics of liquid ⁴H e in con ned geom etries from T im e-D ependent D ensity Functional calculations

Luigi G iacom azzi, Flavio Toigo and Francesco Ancilotto

Istituto Nazionale per la Fisica della Materia and Dipartimento di Fisica "G. Galilei", via Marzolo 8, I-35131 Padova, Italy
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We present numerical results obtained from T im e-D ependent D ensity Functional calculations of the dynam ics of liquid $^4\text{H}\,\text{e}$ in dierent environments characterized by geometrical connement. The time-dependent density prole and velocity eld of $^4\text{H}\,\text{e}$ are obtained by means of direct numerical integration of the non-linear Schrodinger equation associated with a phenomenological energy functional which describes accurately both the static and dynamic properties of bulk liquid $^4\text{H}\,\text{e}$. Our implementation allows for a general solution in 3-D (i.e. no symmetries are assumed in order to simplify the calculations). We apply our method to study the real-time dynamics of pure and alkalidoped clusters, of a monolayer lm on a weakly attractive surface and a nano-droplet spreading on a solid surface.

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I. INTRODUCTION

Density Functional (DF) methods [1] have become increasingly popular in recent years as a useful computational tool to study the properties of classical and quantum inhom ogeneous uids, especially for large systems where the DF methods provides a good compromise between accuracy and computational cost. In particular, a quite accurate description of the T=0 properties of liquid 4H e has been obtained within a DF approach by using the energy functional proposed in Ref.[2] and later improved in Ref.[3]. In general, the Density Functionals for 4H e depend on a number of phenomenological parameters which are adjusted to reproduce bulk experimental properties of liquid 4H e at saturated vapor pressure.

The resulting functionals are found to describe accurately also the properties of the inhom ogeneous systems (e.g. the liquid-vapor interface of the free $^4\text{H}\,\text{e}$ surface) (for a thorough comparison between these and other functionals used to describe liquid $^4\text{H}\,\text{e}$ at T = 0, see Ref.[4]).

This phenom enological functional has been widely used in a variety of problems involving inhom ogeneous ^4He systems like pure and doped clusters [5, 6, 7], electron "bubbles" in bulk ^4He [8], alkaliatom adsorption on the surface of liquid ^4He [9], vortices in ^4He clusters [10], adsorption of liquid ^4He on solid surfaces [11, 12], etc.

A coording to Ref.[3] the static properties of liquid ${}^4\text{He}$ at T=0 are described by the following energy density functional (atom ic units will be used throughout our paper):

$$E_{0}[] = \frac{1}{2M} Z dr (r^{p})^{2} + \frac{1}{2} dr dr^{0} (r) (r^{0})V_{HeHe} (r^{0}) + dr E_{c}(r)$$
(1)

The rst term on the right hand side is the quantum pressure (corresponding to the kinetic energy of a Bose gas of nonuniform density). The second term contains a two-body pair potential $V_{\rm H~e~H~e}$ screened at short distances, while the last term accounts for correlation e ects due to the short-range part of the He-He interaction. The explicit form of the functional is given in Ref.[3], to which the reader is referred for more details (see also the Appendix in the present paper).

The m in im ization of the energy functional (1) with re-

spect to density variations, subject to the constraint of a constant number of $^4{\rm H\,e}$ atom s, (r)dr = N , leads to the equilibrium pro le (r), thus allowing to study the static properties of the $^4{\rm H\,e}$ system .

In order to study the dynam ics of ⁴He an additional term (which has no e ect on the static properties derived from the minim ization of the energy functional (1)) has been added [3] to the functional (1) in the form of a phenom enological current term:

$$H_{J} = \frac{(r)}{2} M v(r)^{2} \frac{M}{4} dr^{0} V_{J} (jr r^{0}j) (r) (r^{0}) [v(r) v(r^{0})]^{2}$$
(2)

The rst term is the usual hydrodynam ic current density, while the second term accounts in a phenom enological way for non-locale ects due to the "back ow" current density β]. The resulting DF (the so-called O rsay-Trento Functional), which will be used in our calculations, has thus the following form:

$$E [;v] = E_0[] + drH_J$$
 (3)

One appealing feature of this functional, which will prove to be essential in the time-dependent calculations presented in the following Sections, is that it reproduces not only the static structure factor but also the bulk dispersion relations of sound excitations in liquid $^4\mathrm{H\,e}$, i.e. the elective current-current interaction V_J in (2) is empirically adjusted in order to reproduce the phonon-roton dispersion curve of bulk $^4\mathrm{H\,e}$ and the dynamic structure function as well.

The extended functional (3) has been applied in the past to the study of density oscillations in ${}^4{\rm H\,e}$ clusters[13], of surface excitations in ${}^4{\rm H\,e}$ lm s [3, 5] and of other related dynam ical phenom ena [14]. In all of the above applications a linear response approximation was used, as well as suitable sym metries were assumed in order to make the calculations feasible.

There are many di erent situations, however, where a more general approach to investigate the microscopic dynam ics of liquid ⁴He in arbitrary environments, often characterized by geom etrical con nem ent, is highly desirable. For instance, modi cations of the excitation spectra due to geom etrical con nem ent are expected in the case of ⁴He lms adsorbed on solid surfaces. A second exam ple involves im purity-doped 4He clusters. Atom ic im purities are currently used as experim ental probes of the superconducting behavior of ⁴He clusters: the coupling of the im purity motion with the cluster dynamics is crucial for a com prehension of the observed spectra. As a third example, we mention the problem of the dynamics of wetting phenomena: weakly attractive surfaces like the heavy alkalim etal surfaces are not wet by liquid ⁴He at very low tem perature, and thus nite amounts of He on these surfaces will form a droplet characterized by a nonzero contact angle. Even on a highly uniform surface, how ever, the contact angle between the 4He droplet and the surface is extremely hysteretic and its value strongly depends on whether the contact line is advancing or receding. Informations from microscopic calculations of the dynam ic behavior of a liquid droplet/ lm spreading on a weak solid surface can represent a valuable help to understand these e ects.

We present here calculations, done in the framework of Time-Dependent Density Functional (TD-DFT) phenomenological theory, of the dynamical properties of $^4\mathrm{He}$ (at T=0) in conned geometries. Our methods allows to calculate the direct real-time evolution of a $^4\mathrm{He}$ system in arbitrary 3. Degeometries. Some applications of the method, showing its eciency and capabilities, will be presented in the following Sections.

II. TIM E-DEPENDENT DENSITY FUNCTIONAL THEORY

In order to extend the DFT scheme described in the previous Section to the domain of time evolution (Time Dependent Density Functional Theory, TD-DFT), one can use a variational principle as follows. One starts from a suitable action integral A written in terms of a complex "wave function" (r;t)

$$A[] = \frac{Z}{\text{dtdr } E[;]} i \frac{Q}{Qt}$$
 (4)

where the energy density E is de ned by E [;v] = R drE. From the condition of stationarity

$$\frac{A}{}=0 \tag{5}$$

a tim e-dependent Euler-Lagrange equation follows:

$$\frac{r^2}{2M} + U[;v] \qquad H = i\frac{\theta}{\theta t} \qquad (6)$$

The "e ective potential" U appearing in the above non-linear time-dependent Schrodinger equation is de ned as the variational derivative of the energy functional, U [;v] E [(r)]= and its explicit expression is given in the Appendix. From the solution e^i of Eq.(6) one can get the time-dependent density $(r;t) = \frac{1}{2}$ and the uid velocity eld v $(r;t) = \frac{1}{2}$.

We describe in the following Section the numerical procedure that we used in order to integrate numerically the Eq.(6) [15].

III. COM PUTATIONAL SCHEME

The num erical solution of eq.(6), i.e. the wave function at an arbitrary timet, (r;t), is obtained by using the Crank-Nicholson's scheme (CN), which enables to evolve (t) to a later timet + t:

$$1 + i \frac{t}{2} H (t + t)$$
 $(t + t) = 1 i \frac{t}{2} H (t)$ (t) (7)

The CN algorithm is one of the many approximate methods that can be used to integrate numerically a time-dependent Schrodinger equation like the one shown in Eq.(6). It is $2^{\rm nd}$ order accurate in t, as can be easily seen by expanding the two sides of Eq.(7) in powers of

t. Am ong the advantages of such scheme is its numerical stability for long-time evolutions, and the unitariness (i.e. the number of particles is conserved during the time evolution) [17]. The CN recursion can be easily solved iteratively for each time step evolution. We not that three iterations are usually enough to guarantee a stable evolution even during long simulation times.

The application of the CN formula requires the calculation of the action of the "Hamiltonian" H U [;v] to the complex wavefunction . A direct evaluation of the potential term U (whose explicit expression is reported in the Appendix) would be prohibitively costly, due to the presence of convolution integrals of the form $I(r) = dr^0 f(r r^0) g(r^0)$, whose evaluation in real space requires a huge number of oating point operations. For such reason we decided to employ a mixed real-reciprocal space representation of the basic quantiand of the density . Since the Fourier transform of a convolution is the product of the Fourier transform s of the two terms entering the integrals, one can perform e ciently the calculations of a convolution integral on a computer by using Fast Fourier Transforms (FFT). The use of FFT implies Periodic Boundary Conditions (PBC), and thus our calculations have been performed using a periodically repeated supercell containing N Helium atoms. Both and are expanded in plane waves: $(r) = {}^{r}_{G} {}^{G} {}^{G} {}^{G} {}^{r}$, and similarly for . The G 's are the supercell wave-vectors, $G = (n=L_x; m=L_y; p=L_z)$, with n;m; p = 0; 1; 2; ... and L_x ; L_y ; L_z are the sides of the supercell (a prim itive orthorhom bic supercell is used in all our calculations). The number of plane waves in the above expansions is chosen such as to give converged values for the total energy E and for the structural param eters of the ⁴He system under investigation. In the various applications that we report in the following, the supercell size was always chosen in such a way to make negligible the interaction of the 4He system with its repeated im ages.

The action of the kinetic energy operator \hat{T} $\frac{1}{2M}$ r 2 on the wavefunction is also evaluated in reciprocal space, i.e.

$$\hat{T} = \frac{1}{2M} F F T f G^2 G g$$
 (8)

Finally, the real-space expression of H , computed as described above, is used in the iteration formula of the CN scheme to give the evolved wave-function (t+ t). A new potential U is thus computed from the updated density and velocity, and the procedure is repeated for the next time-step. Typical time steps t which are found to give stable time evolutions are of the order of 1--3 fem to seconds.

W e stress the fact that no geom etric or $\sin m$ etry constraints are im posed during the time evolution to reduce the computationale ort. Our computational scheme is thus general and can be applied in particular to those situations characterized by geom etrical connement of $^4\text{He.}$ We will give in the following Sections few examples of such case.

IV. ⁴HE BULK EXCITATIONS

One important feature of the most recent implementation of DF for 4 He used here is the inclusion of a "back-

ow " current term (the second term in Equation (2)) explicitly depending on the uid velocity as well as on the uid density, such that the resulting functional is able to correctly reproduce the bulk excitation spectrum of liquid $^4\mathrm{H\,e.}$ This can be immediately veried within our computational scheme as follows.

We setup an initial state corresponding to a modulation of the bulk uniform density with a wave vector q:

$$(r;t=0) = f_0[1 + \sin(q r)]^{\frac{1}{2}}$$
 (9)

where is a small amplitude and $_0=0.02184\,\mathrm{A}^{-3}$ is the saturation density at zero temperature and pressure. The system is then allowed to evolve in time according to the CN scheme described above. By monitoring the periodic oscillations of (r;t) during the simulation, we can immediately calculate the mode frequency:

$$! = \frac{2}{T} = ! (q):$$
 (10)

Here T is the period of the observed oscillation. By varying the wave vector \mathbf{q} we get the whole dispersion curve of ^4He , which we compare in Figure 1 with the experimental data. As it appears from Fig.1, the agreement with the measured data is very good in a wide range of values of the wavevector \mathbf{q} .

W e nally note that if the bulk dispersion relation is calculated by neglecting the "back ow" term in eq.(2), results deviating by as much as 50% from the experimental curva are obtained for $q>0.5\,\mathrm{A}^{-1}$.

V. DYNAM ICS OF ⁴HE CLUSTERS

The dynam ics of liquid ⁴He clusters have been studied theoretically in recent years by means of a number of different methods and thus represents a convenient benchmark for our numerical scheme.

We have considered the monopole and quadrupole vibrationalmodes of cluster of dierent sizes, characterized by the angular momentum quantum number l=0 and l=2, respectively. The dipole mode (l=1) corresponds to a translation of the cluster as a whole, and should thus lie at zero energy. To study the monopole mode, which is a radial breathing oscillation of the cluster density, we compute the main frequencies by monitoring the periodic variations with time of the mean square radius of the cluster:

$$R (t) = \frac{\frac{1}{N}}{\frac{1}{N}} r^{2} (r;t) dr;$$
 (11)

To study the quadrupole oscillations we analyze instead the time evolution of the quadrupole moment tensor Q_{ij} :

$$Q_{ij}(t) = (r_it) \beta r_i r_j r_{ij}^2 ld^3 r_i$$
 (12)

Suitable initial states for both m odes are constructed by applying to the ground state wave function $_0=\frac{p}{eq}$ (where $_{eq}$ represents the equilibrium density prole for the cluster, calculated as described in Section 1 by direct minimization of the energy functional (1)) an excitation operator $e^{i\ F}$, where $F=r^2$ to excite monopole oscillations, while $F=r^2Y_{20}$ to excite quadrupole oscillations:

$$(r;t=0) = e^{i F} _{0}(r)$$
: (13)

This initial state is thus allowed to evolve according to the equation (6). From a frequency analysis of the calculated M (t) and of Q $_{\rm ij}$ (t) we then calculate both the amplitudes and the frequencies of the observed oscillations.

We report in Fig.2 the calculated frequencies of the main oscillations observed in the discrete region of the spectrum (i.e. below the evaporation threshold ! < j j being the chemical potential of a single $^4\text{H}\,\text{e}$ atom).

For com parison, we show in the same F igure the results taken from Ref.[18], obtained within the Random Phase Approximation (RPA) and using a zero-range Density Functional to describe the $^4\mathrm{He}$ system. The approach used in Ref.[18], which neglects completely the short-range He-He correlation e ects, is accurate only when applied to the study of excitations involving variations in space larger than the average distance between the $^4\mathrm{He}$ atoms: this is not, however, a major limitation for the long-wavelength modes like the ones investigated here (external eld proportional to $^1\mathrm{Y}_{10}$ (?).

In the same plot we compare also our calculated frequencies with those obtained from more recent calculations done by using a nite-range DF including non-locale ects, very similar to the one used here, and again within RPA [6]. The results are not much dierent from those obtained using a zero-range functional[18], showing that the elects of non-localities are not important in this case due to the q=0 character of the multipole excitations studied here.

Our calculated values, as it appears from Fig.2, do not dier much from the two previous theoretical results, even if they are obtained by explicitly including the "back ow" term (see Eq.(2)) in the He density functional. The reason is that this term becomes in portant in the region where the bulk dispersion relation deviates from its phonon-like behavior, whereas in the present case only low-q excitations are considered. In the next sections we will present cases where the inclusion of the back ow term is instead crucial in order to get accurate results.

VI. EXCITATIONS OF A ⁴HE M ONOLAYER ADSORBED ON A W EAKLY ATTRACTIVE SURFACE

The study of the structure, growth and excitations of liquid $^4{\rm H\,e}$ lms adsorbed on solid surfaces is an important eld of current research on super uid properties.

Reliable theories of inhom ogeneous liquid $^4{\rm He}$ m ay represent a useful complementary tool for studying the properties of liquid $^4{\rm He}$ interacting with a solid surface[19].

Because of the extremely weak HeHe interaction, liquid ⁴He in contact with almost any substrate spreads to form a continuous Im over the surface, so that vapor and substrate are never in contact. A remarkable exception to this behavior is found when ⁴He is adsorbed on heavy alkalimetal surfaces: due to the large electron spill-out at these surfaces, alkalimetals provide the weakest adsorption potentials in nature for He atoms. Based on this observation, it was suggested [20, 21] that ⁴Hem ight not wet some heavy alkalimetal surfaces. Subsequent experiments have conmed this remarkable prediction [22, 23, 24, 25].

We study here the excitations of a single monolayer of liquid $^4\mathrm{H}\,\mathrm{e}$, adsorbed on a weakly attractive surface. We choose here the surface of Rb: this is because Rb is the weakest surface that it is actually wet by $^4\mathrm{H}\,\mathrm{e}$ at T - 0, i.e. the stable state of liquid $^4\mathrm{H}\,\mathrm{e}$ on Rb is represented by a thin liquid - movering the whole surface, rather than being represented by a droplet as in the case of Cs. The extremely weak He-surface interaction on the other hand is expected to act as a small perturbation on the - m. Thus the excitations studied here should be representative to some extent of those for an isolated $^4\mathrm{H}\,\mathrm{e}$ - lm.

To model the interaction with a Rb substrate, we use a binding potential V_s (z) which describes the interaction between Rb, occupying the half space z 0, and one 4 He atom located at a distance z above the surface, which is taken to be ideally at. The explicit form for V_s (z), originally proposed in Ref.[27], has been later revised in Ref.[12] in order to correctly reproduce the experimental wetting properties of the 4 He/Rb system. We do not include any corrugation of the surface on the atom ic scale to m in ic its actual microscopic structure. This is a good approximation for the case of 4 He adsorption on alkalimetal surfaces, because the experiments [28] indeed indicate that a surprisingly smooth surface is seen by adsorbed 4 He atom s.

The total energy functional of liquid $^4\mathrm{He}$ interacting with a Rb surface is thus described by the energy functional (3) augmented by the additional term

dr (r)V $_{\rm S}$ (r), which describes the interaction energy due to the presence of the surface. We have prelim inarly studied the equilibrium density of liquid $^4{\rm He}$ on the Rb surface, at dierent areal coverages. Our results are reported in Fig.3, where the density proles in the direction perpendicular to the surface (which is located at z = 0) are shown. Note that as the coverage increases, a second layer starts to form above the rst layer. Quite arbitrarily, we take as representative of a "monolayer" the prole shown in Fig.3 with a thicker line, corresponding to n = 4.2 10^{-2} A 2 .

We thus prepare our monolayer in a suitable nonequilibrium initial state, characterized by a density modulation with a wave-vector q parallel to the surface. We note that, due to the presence of a sym m etry-breaking external potential (the He-surface potential) which depends on z (the coordinate normal to the surface), such initial state will be im mediately coupled, during its time-evolution, to excitations of the lm polarized perpendicularly to the surface plane.

From a Fourier analysis of the density variations during the time evolution from this initial state, we are able to get the main excitations of the $^4\mathrm{He}$ lm. Fig. 4 shows our results. The lled and empty squares show the main features observed in the frequency spectrum of the time-dependent density (r;t). The lled squares indicate the most intense peaks, whereas the open squares indicate the somewhat weaker features in the spectrum.

For comparison we also show with solid line the experimental "ripplon" dispersion relation [29]. It appears from Fig.4 that at low q values the lower dispersion curve becomes softer that the ripplon curve. This is not surprising since the ripplon dispersion, which relates to the surface excitations of a in nite half-space occupied by the liquid, is altered by the nite thickness of the lim. A simple model calculation [30] gives in fact for the oscillation frequency of a thin ⁴He lim of thickness a in the low-q lim it:

! (q) !
$$_{ripplon}$$
 (q) (qa) $^{1=2}$ (14)

 q^{3-2} , the expected dispersion scales as Since!ripplon q^2 , in qualitative agreem ent with our ndings. A lthough a de nite character cannot be assigned unambiguously to the observed mode shown in Fig.4 due to the strong m ixing between the two bands, we suggest that the upper branch should have a strong component of density m odulations perpendicular to the surface. To verify this we have induced in the monolayer a sim ple q = 0 m odewhere the ⁴He lm is initially rigidly shifted (by a very sm all am ount) towards the surface. Due to the presence of the holding He-surface potential, the Im once let free to evolve, execute a motion where it executes oscillations m ainly perpendiculto the surface, with a main frequency at about 5 K: this value is shown with a led dotat q = 0 in Fig.4.

We can compare our results for the lm excitations with those obtained in Ref.[26] by means of a microscopic statistical theory, where the dynamic excitations of thick 4 He $\,$ lms on a Cs surface were considered. In that work it is found that ripplon modes appear in the calculated spectra, whose dispersion follows the q3=2 law for surface excitations, as well as "interfacial" ripplons localized mainly at the 4He/surface interface. In particular, the lowest mode calculated in Ref.[26] (corresponding the the lower branch in Fig.4) has a ripplon character. The second mode has a "longitudinal" character (i.e. parallel to the surface) on stronger substrates, only on very weak surfaces (i.e. Cs) it has a visible perpendicular component. A linear (third sound) dispersion has been also observed in Ref. [26] as long as the wavelength is large compared with the lm thickness. We do not observe any such ${\tt m}$ odes, probably because of the ${\tt n}$ ite thickness of our system .

We believe that the upper branch in Fig.4 is the counterpart of a sim ilar excitations observed in neutron di raction experiments on ⁴He adsorbed on a graphite substrate[31], where, among other excitations, almost dispersionless modes at low frequencies have been observed. These mode have been interpreted [32], by means of microscopic calculations, as standing waves of the ⁴He liquid perpendicular to the substrate. We cannot compare directly our results with the experim entalm easurements of [31] and with the microscopic calculations of Ref.[32] because of the dierent substrate used (graphite is a much "stronger" substrate than alkalim etal surfaces) and because multy layer Imswere considered in these references. We hope that our results will stimulate further experim ental measurements, in particular to study the excitations of 4He m onolayers on weakly attractive sur-

VII. DYNAM ICS OF ALKALI-DOPED ⁴HE CLUSTERS

The spectroscopy of doped liquid ⁴He clusters has become a current tool for the study of super uidity in ⁴He droplets[33]. As a consequence of the ultra-weak alkali-He interaction, an alkali atom picked up by a ⁴He cluster has its stable state in a "dimple" on the surface of the cluster[9, 34], rather than being solvated into its interior like most of the other atom ic in purities. Thus alkali could provide an excellent probe for the surface excitation of super uid nanodroplets[34].

The analysis and interpretation of experim ental studies of the form ation of $^4\mathrm{H}$ e-alkali complexes in doped clusters would bene t from theoretical work of the excitations of impurities attached to $^4\mathrm{H}$ e clusters.

Although for light alkali the motion of the impurity can be considered to a rst approximation as occurring in a static ^4He environment (i.e. He does not adjust appreciably to the istantaneous atom position), however, for heavy alkali (Rb,Cs) a full dynamical approach is required, where the ^4He atoms in the cluster are allowed to adjust dynamically upon the motion of the adsorbed impurity.

We address here the problem of nding the spectrum of vibrational excitations of a "dimple" state. We consider in particular the system composed of a single Rb atom (in its electronic ground-state) attached to a 300-atom ⁴He cluster. The Rb-He interaction is taken from Ref.[35].

Fig. 5 shows the calculated equilibrium density pro le (in a plane containing the center of the cluster and the Rb atom) for the "dim ple" state representing the lowest energy con guration of the Rb $^4\mathrm{H}\,\mathrm{e}$ system .

By applying to the Rb atom a small initial momentum towards the surface of the cluster, we observe that the impurity starts oscillating around its equilibrium position shown in Fig. 5, and at the same $time the {}^4He$

density changes in time to adjust dynam ically to the istantaneous Rb position. Our results for the Rb dynam ics are shown in Fig.6. In the upper panel we show the calculated istantaneous position of the Rb atom as a function of time (measured with respect to the Rb-cluster center-of-mass). A straightforward Fourier transform of the signal shown in the upper panel allows to compute the frequency spectrum shown in the lower panel.

We compare our results with a previous estimate [36] based on static DF calculations, where the frequency of the oscillations of a Rb atom attached to a 300-atom cluster was estimated approximately by assuming that the He atoms adiabatically adjusted to the istantaneous position of the impurity. In that case the value of the frequency was extracted from the shape of the impurity-He potential energy surface, giving! 0:7K. It appears from our results that a more complex dynamics results, due to the coupling of the Rb atom motion with the surface oscillations of the cluster. The frequency of a surface m_0 ode of an N-atom p^4 He cluster can be written as $\overline{1(1 \ 1)(1+2)!_0} = \overline{N}$ where $!_0 = 3.45$ K. This is approxim ately 0.6K for the lowest l=2 m ode, i.e. close to the natural Rb frequency calculated in Ref.[36]. A large amount of mixing is thus expected, which determ ines the appearance of the complex vibrational spectrum shown in Fig.6.

Experimental measurements of such oscillations are underway [37] to con mour predictions. A more complex and challenging application of time-dependent methods, i.e. the study of the oscillations of an alkali in purity in an excited electronic state, is currently in progress.

VIII. SPREADING OF A 4 HE NANODROPLET ON A W EAKLY ATTRACTIVE SUBSTRATE

The mechanism underlying the spreading of a liquid droplet on a solid substrate is a long-standing problem . Experiments done on a number of dierente (classical) molecular uids have revealed universal laws such as the Tanner' spreading law [38], where the droplet radius grows as $r(t) / t^{l=10}$, as well as fascinating phenomena on the atom istic scale (such as the appearence of a monolayer lm advancing in front of the drop [39], two dierent regimes of the growth of the radius with time [40], dynamical "layering", etc.). O ther experiments [39] have shown that one or more monomolecular precursor layers spread ahead of the droplet cap with an average radius R (t) t.

Num erical studies of droplet spreading have been performed [40, 41, 42, 43] in recent years. Despite many e orts, however, many microscopic details of the spreading process are however still to be known.

Even more challenging is the behavior of a super uid ⁴He droplet on a weakly attractive surface: it has been found that ⁴He droplets adsorbed on a Cs substrate have spreading and ow properties that are not simple consequences of bulk super uid behavior[44]. When a ⁴He

droplet is deposited on a Cs surface (the only material known that is not wetted by super uid ⁴He at very low temperature), even on a highly uniform surface the contact angle between the droplet and the surface is extremely hysteretic and its value strongly depends on whether the contact line is advancing or receding. Super uid ⁴He droplets on Cs are also remarkable because they can resist ow against a substantial chemical potential gradient [44].

We have studied the spreading of a 200-atom He cluster on a weakly attractive surface. We choose for the latter the case of Cs (but very sim ilar results are obtained for a Rb surface). To simulate the Cs surface, we use the "ab initio" potential developed in Ref. [27], which has applied successfully to the wetting properties of He an a Cs surface [12]. The initial state is represented by a spherical cluster (whose density prole is obtained by minimization of the static functional (2) in the absence of the attractive He-surface potential), placed in the vicinity of the surface. The downward force responsible for the spreading of the droplet is provided solely by the long-range Van der Waals forces exerted by the substrate (due to the microscopic size of the droplet, the elect of gravity on spreading is negligible).

The spreading will continue, until the stable state is eventually reached. The nature of the latter depends on the strength of the He-surface potential: in the case of C s, which is not wet by He at T = 0, the nalcon guration will be that of an almost spherical cap characterized by a contact angle of 40 (partial wetting behavior) [11, 44]. More attractive substrate, on the other hand, will eventually be covered by a uniform microscopic lm (complete wetting behavior). Due to the niteness of our systems and our use of periodic boundary conditions our simulations are necessarily interrupted when the droplet hits its repeated in ages and starts coalescing with them.

The sequence characterized the spreading process is shown in Fig.7. The overall duration of the simulation shown in the Figure is about 2ns. Interestingly enough, a precursor layer seems to form under the cap of the spreading cluster. We have computed from the cluster density pro le (r;t) the average radius R of this precursor layer. The dependence of R from the time, shown in Fig.8, shows a "fast" regime where the precursor layer expands linearly in time, as found in similar simulations for classical uids [43]. Then a slowing down occurs, in correspondence of the form ation of the second layer (see panel (f) in Fig.7). It seems that after a transient, an almost linear spreading occurs again, although with a som ew hat lower velocity. The speed from the linear portion of Fig. 8 gives a velocity of about 50 m = s, which is close to the critical Landau velocity. The slowing down is perhaps due to the spontaneous formation of vorticalrings during the spreading. One such ring is shown in Fig.9 by means of a vector plot showing the current density J (r)v(r) in a plane containing the center of the cluster and perpendicular to the Cs surface. Fig.9 also clearly shows the ow of atoms from the droplet cap

feeding the underlying precursor lm.

Although transient precursor $\ln s$ spreading linearly with time has been obtained from MD simulations of classical uids [41, 43], they have not been seen in any experiment. This is probably due to the fact that they represent the very early stage of the spreading process: as the equilibrium shape of the droplet is reached, the initial fast spreading is found to slow down to a power law R (t) $t^{1=7}$ [45], when a regime dominated by dissipation due to the viscous ow starts to dominate. It would be extremely interesting to study how this slowing down (which is only suggested from our short-time results in Fig.8) occurs in the case of super uid ow.

The presence of surface disorder is expected to alter the dynam ics of liquid ⁴He lms spreading on a solid surface, because the three-phase contact line of the spreading lm/droplet can easily be pinned to these defects, modifying the velocity of the contact line as it advances (or recedes) on the surface. We are currently investigating the elect of simple defects on the atom ic-scale (adatoms or vacancies) on the droplet spreading process discussed above.

IX. SUMMARY

We have presented TD-DFT calculations of the dynam ical properties of ${}^4{\rm H}\,{\rm e}$ in situations characterized by

geom etrical con nem ent. We have shown the feasibility and e ciency of fully 3-D TD-DFT calculations to study the dynam ics of liquid He-4 in a number of representative situations: the dynam ics of pure and alkali-doped ⁴He clusters, the excitations of a liquid ⁴He monolayer adsorbed on a weakly attractive surface and the dynam ics of a ⁴He nano-droplet spreading on a Cs surface.

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Appendix

The e ective potential entering Eq.(6) can be readily evaluated by functional di erentiation of the energy functional (3) (see Ref.[3] for its detailed expression):

 $V_{\rm s}$ (r) represents an additional external potential acting on the $^4{\rm H\,e}$ system . The second term contains a two-body $^4{\rm H\,e}^4{\rm H\,e}$ pair potential $V_{\rm s}$ (r) screened at distances shorter than a characteristic length h., while the third and the fourth term (correlation terms), which contains the average of the density over a sphere of radius h., r, accounts for the internal kinetic energy and for the increasing contribution of the hard-core He-He repulsion when the density is increased. The last two terms represent the contribution to the potential U of the "backow" term (2) introduced in Ref.[3] in order to reproduce the bulk excitation spectrum of liquid $^4{\rm H\,e}$. In particu-

lar, the last term contains the "back ow" current J_B $dr^0g(r;r^0) = dr^0V_J(\dot{r} r^0\dot{j})$ (r) (r^0) (v (r) v (r^0))

The free param eters h_1, c_2, c_3, c_3 are adjusted in order to reproduce a number of experim ental properties of bulk liquid $^4\mathrm{H}\,\mathrm{e}$. For a detailed description of the various terms and the numerical values of the adjustable parameters, we refer the interested reader to Ref.[3].

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Figure Captions

Figure 1: Bulk 4 He excitation spectrum. The points show the calculated spectrum, while the solid line shows the experimental dispersion relation.

Figure 2: Calculated monopole (upper lines) and quadrupole (lower lines) oscillation frequencies of liquid ⁴He clusters, shown as a function of the cluster sizes. Dots: this work; squares: results from Ref.[18]; triangles: results from Ref.[6].

Figure 3: Equilibrium density pro les for $^4{\rm He}$ lms adsorbed on a Rb surface. The z direction is perpendicular to the surface plane. Di erent curves represent increasing values of the surface coverages (number of $^4{\rm He}$ atoms per unit surface area), from n = 1:6 10 $^2{\rm A}$ 2 (lower pro le) to n = 72 10 $^2{\rm A}$ 2 (upper pro le). The thicker line (de ning our "monolayer") is drawn at n = 42 10 $^2{\rm A}$ 2 .

Figure 4: Calculated dispersion curves for a 4 Hem ono—layer adsorbed on a Rb surface (squares). The dotted line is the bulk dispersion relation, while the solid line shows the experimental "ripplon" dispersion.

Figure 5: Density contour plot for a 300-atom ⁴He cluster with a Rb atom attached on its surface: the dot shows the equilibrium position of the Rb impurity.

Figure 6: Upper panel: Rb displacement with respect to the center-ofm assofthe Rb-cluster system, measured along the radial direction, as a function of the simulation time. Lower panel: Fourier spectrum (in arbitrary units) of the time series shown in the upper panel.

Figure 7: Sequence of ⁴He density contour plots show – ing the spreading of a 200-atom cluster on a Cs surface.

Figure 8: Radius of the precursor layer as a function of $\mbox{tim}\,\mbox{e.}$

Figure 9: Vector plot of the current density v in a plane perpendicular to the surface and passing through the center of the cluster. The conguration shown corresponds to the density contours in panel (e) of Fig.7.

















